

# IGBT MODULE

# GCA200AA120



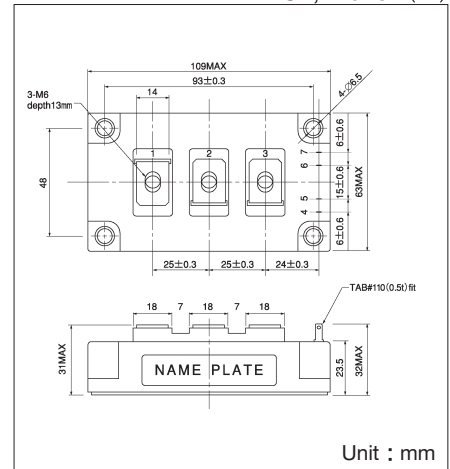
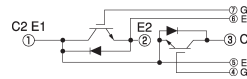
UL;E76102 (M)

**SanRex** IGBT Module **GCA200AA120** is designed for high speed, high current switching applications. This Module is electrically isolated and contains two IGBTs connected in series with a fast switching, soft recovery diode ( $t_{rr}=0.1 \mu s$ ) reverse connected across each IGBT.

- $I_c=200A$   $V_{CES}=1200V$
- $V_{CE(sat)}=3.0V$  Typ
- $t_f=0.10 \mu s$  Typ
- Soft recovery diode

### (Applications)

- Inverter for motor control (VVVF)
- UPS, AC servo
- DC power supply, Welder



### Maximum Ratings

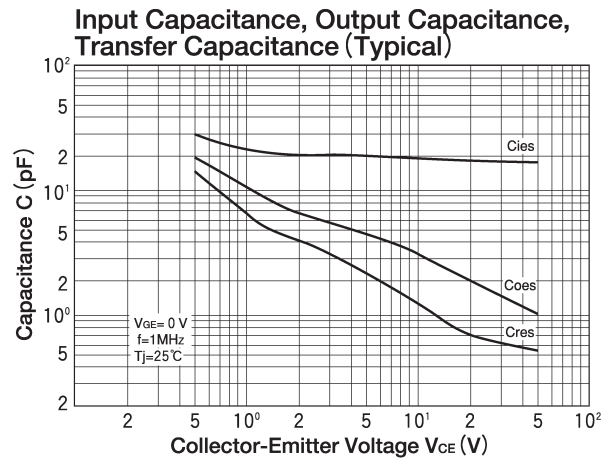
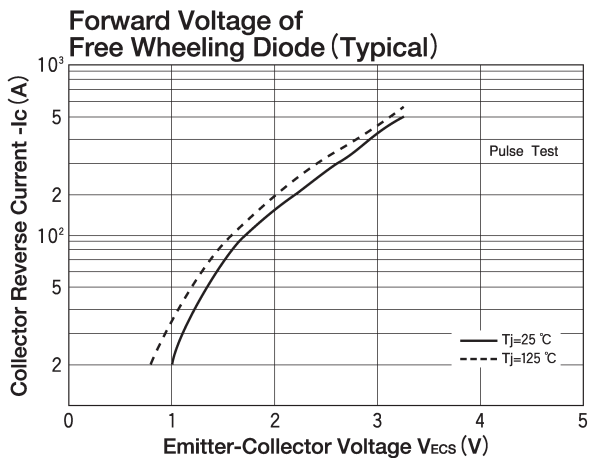
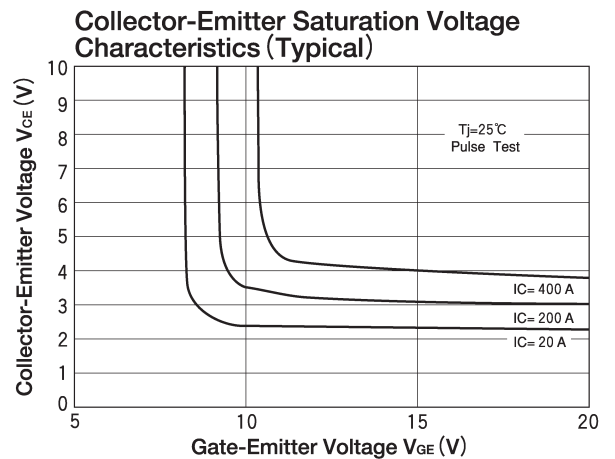
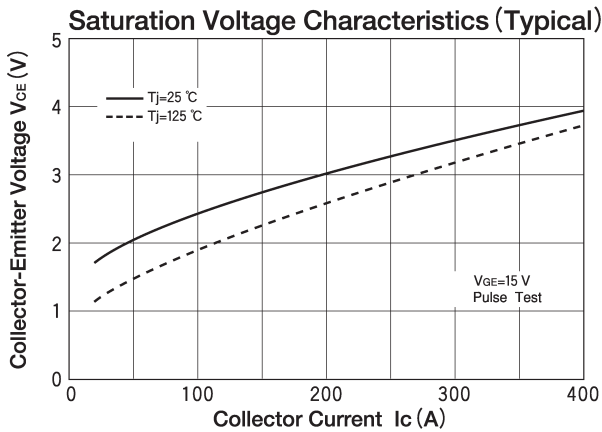
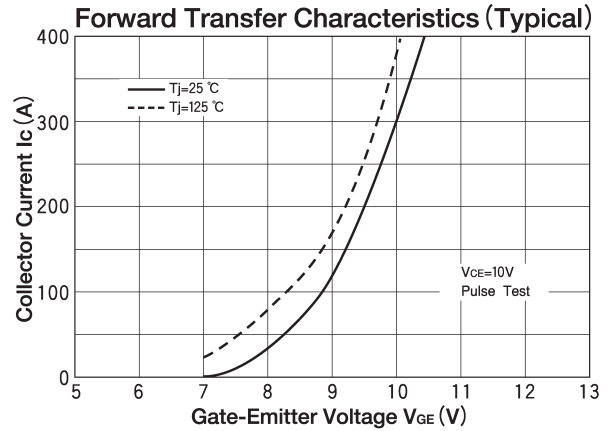
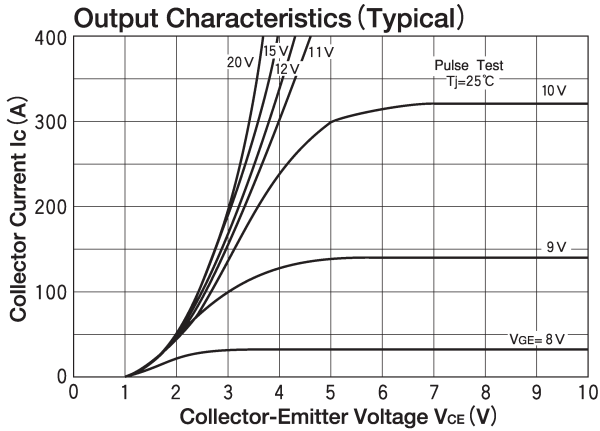
(Unless otherwise  $T_j=25^\circ C$ )

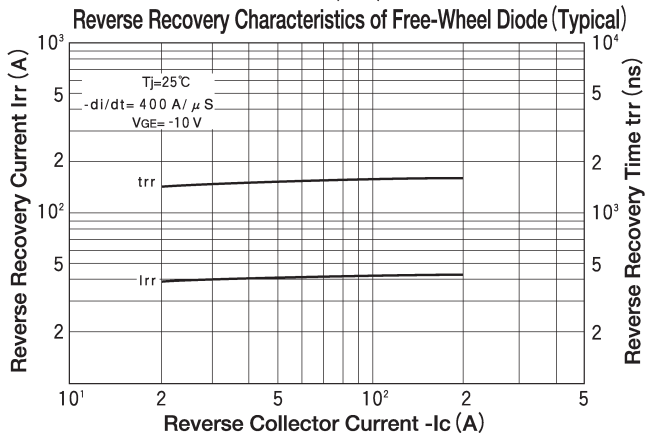
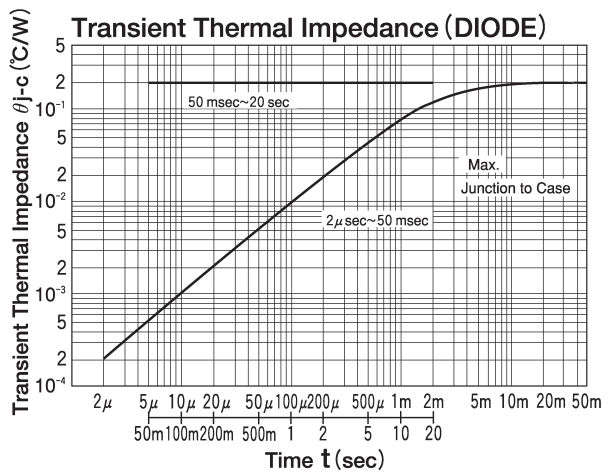
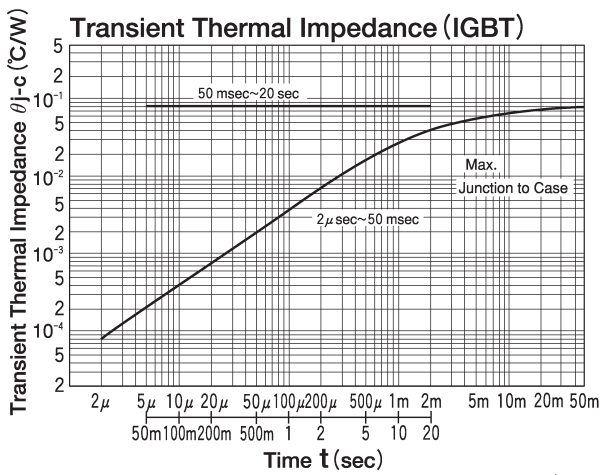
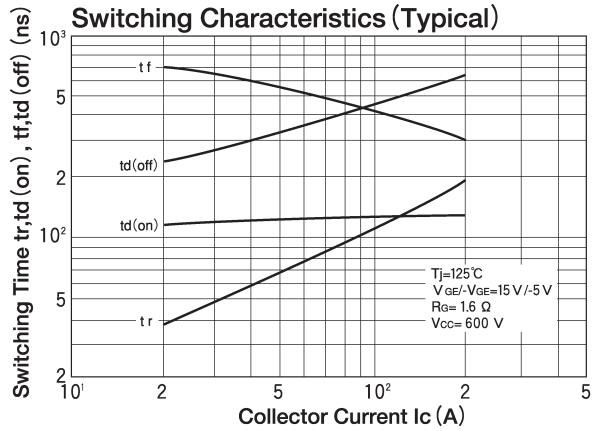
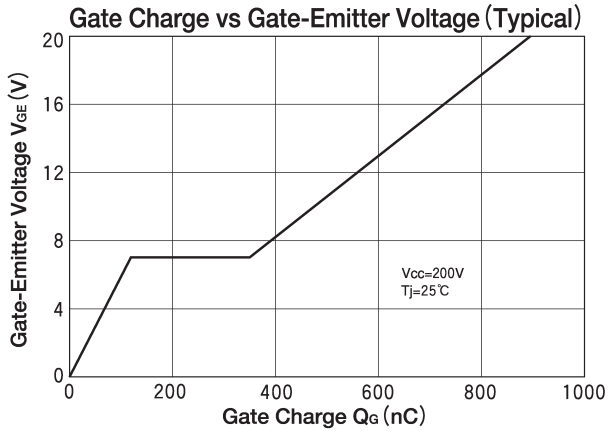
Symbol	Item		Conditions	Ratings			Unit
				GCA200AA120			
$V_{CES}$	Collector-Emitter Voltage		with gate terminal shorted to emitter	1200			V
$V_{GES}$	Gate-Emitter Voltage		with collector shorted to emitter	$\pm 20$			V
$I_c$	Collector Current	DC		200			A
$I_{CP}$		Pulse ( 1 ms)		400			
$-I_c$	Reverse Collector Current			200			A
$P_T$	Total Power Dissipation		$T_c=25^\circ C$	1500			W
$T_j$	Junction Temperature			150			$^\circ C$
$T_{stg}$	Storage Temperature			$-40 \sim +125$			$^\circ C$
$V_{ISO}$	Isolation Voltage (R.M.S.)		A.C. 1 minute	2500			V
	Mounting Torque	Mounting (M6)	Recommended Value 2.5~3.9 (25~40)	4.7 (48)			N·m (kgf·cm)
		Terminal (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)			
	Mass		Typical Value	400			g

### Electrical Characteristics

(Unless otherwise  $T_j=25^\circ C$ )

Symbol	Item		Conditions	Ratings			Unit
				Min.	Typ.	Max.	
$I_{GES}$	Gate Leakage Current		$V_{GE}=\pm 20V, V_{CE}=0V$			$\pm 500$	nA
$I_{CES}$	Collector Cut-Off Current		$V_{CE}=1200V, V_{GE}=0V$			1.0	mA
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage		$V_{GE}=0V, I_c=1 \text{ mA}$	1200			V
$V_{GE(th)}$	Gate Threshold Voltage		$V_{CE}=10V, I_c=20 \text{ mA}$	4.5		7.5	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage		$I_c=200A, V_{GE}=15V$		3.0	3.4	V
$C_{ies}$	Input Capacitance		$V_{CE}=10V, V_{GE}=0V, f=1 \text{ MHz}$		20	40	nF
$t_r$	Switching Time	Rise Time	$I_c=200A, V_{GE}=+15V/-5V$ $V_{CC}=600V, R_G=1.6 \Omega$		0.10	0.25	$\mu s$
$t_{d(on)}$		Turn-on Delay Time			0.15	0.35	
$t_f$		Fall Time			0.10	0.35	
$t_{d(off)}$		Turn-off Delay Time			0.35	0.50	
$V_{ECS}$	Emitter-Collector Voltage		$-I_c=200A, V_{GE}=0V$		2.20	3.50	V
$t_{rr}$	Reverse Recovery Time		$-I_c=200A, V_{GE}=-10V, di/dt=400A/\mu s$		0.15	0.25	$\mu s$
$R_{th(j-c)}$	Thermal Resistance		IGBT-Case			0.08	$^\circ C/W$
			Diode-Case			0.20	





This datasheet has been downloaded from:

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Datasheets for electronic components.